

### <span id="page-0-0"></span>**FEATURES**

**High speed 120 MHz bandwidth, gain = −1 230 V/µs slew rate 90 ns settling time to 0.1% Ideal for video applications 0.02% differential gain 0.04° differential phase Low noise 1.7 nV/√Hz input voltage noise 1.5 pA/√Hz input current noise Excellent dc precision 1 mV maximum input offset voltage (over temperature) 0.3 µV/°C input offset drift Flexible operation Specified for ±5 V to ±15 V operation ±3 V output swing into a 150 Ω load External compensation for gains 1 to 20 5 mA supply current Available in tape and reel in accordance with EIA-481A standard**

#### <span id="page-0-1"></span>**GENERAL DESCRIPTION**

The  $36*$ S+ is a low noise (1.7 nV/ $\sqrt{Hz}$ ), high speed op amp with custom compensation that provides the user with gains of 1 to 20 while maintaining a bandwidth >50 MHz. Its 0.04° differential phase and 0.02% differential gain performance at 3.58 MHz and 4.43 MHz, driving reverse-terminated 50  $\Omega$  or 75  $\Omega$  cables, makes it ideally suited for professional video applications. The AD829 achieves its 230 V/µs uncompensated slew rate and 750 MHz gain bandwidth while requiring only 5 mA of current from power supplies.

The external compensation pin of the AD829 gives it exceptional versatility. For example, compensation can be selected to optimize the bandwidth for a given load and power supply voltage. As a gain-of-2 line driver, the −3 dB bandwidth can be increased to 95 MHz at the expense of 1 dB of peaking. Its output can also be clamped at its external compensation pin.

The AD829 exhibits excellent dc performance. It offers a minimum open-loop gain of 30 V/mV into loads as low as 500 Ω, a low input voltage noise of 1.7 nV/√Hz, and a low input offset voltage of 1 mV maximum. Common-mode rejection and power supply rejection ratios are both 120 dB.

This op amp is also useful in multichannel, high speed data conversion where its fast (90 ns to 0.1%) settling time is important. In such applications, the AD829 serves as an input buffer for 8-bit to 10-bit ADCs and as an output I/V converter for high speed DACs.

#### **Rev. I**

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# High Speed, Low Noise Video Op Amp

### **CONNECTION DIAGRAM**

<span id="page-0-2"></span>

*Figure 1. 8-Lead PDIP (N), CERDIP (Q), and SOIC (R)* 



*Figure 2. 20-Terminal LCC* 

Operating as a traditional voltage feedback amplifier, the AD829 provides many of the advantages that a transimpedance amplifier offer. A bandwidth >50 MHz can be maintained for a range of gains through the replacement of the external compensation capacitor. The AD829 and the transimpedance amplifier are both unity-gain stable and provide similar voltage noise performance  $(1.7 \text{ nV}/\sqrt{\text{Hz}})$ ; however, the current noise of the AD829  $(1.5 \text{ pA}/\sqrt{\text{Hz}})$  is less than 10% of the noise of transimpedance amplifiers. The inputs of the AD829 are symmetrical.

### <span id="page-0-3"></span>**PRODUCT HIGHLIGHTS**

- 1. The input voltage noise of 2 nV/ $\sqrt{Hz}$ , current noise of 1.5 pA/√Hz, and 50 MHz bandwidth for gains of 1 to 20 make the AD829 an ideal preamp.
- 2. A differential phase error of 0.04 and a 0.02% differential gain error, at the 3.58 MHz NTSC, 4.43 MHz PAL, and SECAM color subcarrier frequencies, make the op amp an outstanding video performer for driving reverse-terminated 50 Ω and 75 Ω cables to  $\pm$ 1 V (at their terminated end).
- 3. The AD829 can drive heavy capacitive loads.
- 4. Performance is fully specified for operation from ±5 V to  $\pm$ 15 V supplies.
- 5. The AD829 is available in PDIP, CERDIP, and small outline packages. Chips and MIL-STD-883B parts are also available. The 8-lead SOIC is available for the extended temperature range (−40°C to +125°C).

# **TABLE OF CONTENTS**



# <span id="page-1-0"></span>**REVISION HISTORY**



## 4/09-Rev. G to Rev. H



## $4/04$  -- Rev. F to Rev. G





#### $2/03$ -Rev. E to Rev. F



# <span id="page-2-0"></span>**SPECIFICATIONS**

T<sub>A</sub> = 25°C and V<sub>s</sub> = ±15 V dc, unless otherwise noted.

## **Table 1.**



<span id="page-3-0"></span>

<sup>1</sup> Full power bandwidth = slew rate/2 π V<sub>PEAK</sub>.<br><sup>2</sup> Tested at gain = 20, C<sub>COMP</sub> = 0 pF.

<sup>3</sup> 3.58 MHz (NTSC) and 4.43 MHz (PAL and SECAM).

<sup>4</sup> Differential input capacitance consists of 1.5 pF package capacitance plus 3.5 pF from the input differential pair.

# <span id="page-4-0"></span>ABSOLUTE MAXIMUM RATINGS

#### **Table 2.**



 $1$  Maximum internal power dissipation is specified so that T<sub>J</sub> does not exceed 150°C at an ambient temperature of 25°C.

<sup>2</sup> If the differential voltage exceeds 6 V, external series protection resistors should be added to limit the input current.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### <span id="page-4-1"></span>**THERMAL CHARACTERISTICS**

**Table 3.** 



#### <span id="page-4-2"></span>**METALLIZATION PHOTO**



*Figure 3. Metallization Photo; Contact Factory for Latest Dimensions, Dimensions Shown in Inches and (Millimeters)* 



*Figure 4. Maximum Power Dissipation vs. Temperature*

## <span id="page-4-3"></span>**ESD CAUTION**



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# <span id="page-5-0"></span>TYPICAL PERFORMANCE CHARACTERISTICS



*Figure 5. Input Common-Mode Range vs. Supply Voltage*







*Figure 7. Output Voltage Swing vs. Resistive Load*



*Figure 10. Closed-Loop Output Impedance vs. Frequency*













*Figure 14. Open-Loop Gain and Phase vs. Frequency*







*Figure 16. Power Supply Rejection Ratio (PSRR) vs. Frequency*



*Figure 17. Common-Mode Rejection Ratio (CMRR) vs. Frequency*











*Figure 20. Total Harmonic Distortion (THD) vs. Frequency*







#### **400 AV = +20 SLEW RATE 10% TO 90% 350 RISE** SLEW RATE (V/µs) **300 SLEW RATE (V/µs)**  $V_S = \pm 15V$ **FALL 250 RISE 200 FALL 150** 23 00880-023  $V_S = \pm 5V$ **100 140 –60 –40 –20 0 20 40 60 80 100 120 TEMPERATURE (°C)**









*Figure 25. Gain-to-2 Follower Large Signal Pulse Response (Se[e Figure 32\)](#page-10-1)* 



*Figure 26. Gain-of-2 Follower Small Signal Pulse Response (Se[e Figure 32\)](#page-10-1)* 



*Figure 27. Gain-of-20 Follower Large Signal Pulse Response (Se[e Figure 33\)](#page-10-2)* 



*Figure 28. Gain-of-20 Follower Small Signal Pulse Response (Se[e Figure 33\)](#page-10-2)* 





# <span id="page-10-0"></span>TEST CIRCUITS



*Figure 31. Offset Null and External Shunt Compensation Connections* 



*Figure 32. Follower Connection, Gain = 2* 

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*Figure 33. Follower Connection, Gain = 20*



<span id="page-10-3"></span>

# <span id="page-11-0"></span>THEORY OF OPERATION

The AD829 is fabricated on the Analog Devices, Inc., proprietary complementary bipolar (CB) process, which provides PNP and NPN transistors with similar  $f_{TS}$  of 600 MHz. As shown in [Figure 35,](#page-11-3) the AD829 input stage consists of an NPN differential pair in which each transistor operates at a 600 µA collector current. This gives the input devices a high transconductance, which in turn gives the AD829 a low noise figure of 2 nV/ $\sqrt{Hz}$  at 1 kHz.



*Figure 35. Simplified Schematic*

<span id="page-11-3"></span>The input stage drives a folded cascode that consists of a fast pair of PNP transistors. These PNPs drive a current mirror that provides a differential-input-to-single-ended-output conversion. The high speed PNPs are also used in the current-amplifying output stage, which provides a high current gain of 40,000. Even under heavy loading conditions, the high f<sub>TS</sub> of the NPN and PNPs, produced using the CB process, permit cascading two stages of emitter followers while maintaining 60 phase margin at closed-loop bandwidths greater than 50 MHz.

Two stages of complementary emitter followers also effectively buffer the high impedance compensation node (at the C<sub>COMP</sub> pin) from the output so that the AD829 can maintain a high dc openloop gain, even into low load impedances (92 dB into a 150  $\Omega$ ) load and 100 dB into a 1 kΩ load). Laser trimming and PTAT biasing ensure low offset voltage and low offset voltage drift, enabling the user to eliminate ac coupling in many applications.

For added flexibility, the AD829 provides access to the internal frequency compensation node. This allows users to customize the frequency response characteristics for a particular application.

Unity-gain stability requires a compensation capacitance of 68 pF (Pin 5 to ground), which yields a small signal bandwidth of 66 MHz and slew rate of 16 V/ $\mu$ s. The slew rate and gain bandwidth product varies inversely with compensation capacitance. [Table 4](#page-12-1) an[d Figure 37](#page-11-4) show the optimum compensation capacitance and the resulting slew rate for a desired noise gain.

For gains between 1 and 20, choose C<sub>COMP</sub> to keep the small signal bandwidth relatively constant. The minimum gain that will still provide stability depends on the value of the external compensation capacitance.

An RC network in the output stage (se[e Figure 35\)](#page-11-3) completely removes the effect of capacitive loading when the amplifier compensates for closed-loop gains of 10 or higher. At low frequencies, and with low capacitive loads, the gain from the compensation node to the output is very close to unity. In this case, C is bootstrapped and does not contribute to the compensation capacitance of the device. As the capacitive load increases, a pole forms with the output impedance of the output stage, which reduces the gain, and subsequently, C is incompletely bootstrapped. Therefore, some fraction of C contributes to the compensation capacitance, and the unity-gain bandwidth falls. As the load capacitance is further increased, the bandwidth continues to fall, and the amplifier remains stable.

## <span id="page-11-1"></span>**EXTERNALLY COMPENSATING THE AD829**

The AD829 is stable with no external compensation for noise gains greater than 20. For lower gains, two different methods of frequency compensating the amplifier can be used to achieve closed-loop stability: shunt and current feedback compensation.

### <span id="page-11-2"></span>**SHUNT COMPENSATION**

[Figure 36](#page-11-5) an[d Figure 37](#page-11-4) show that shunt compensation has an external compensation capacitor, C<sub>COMP</sub>, connected between the compensation pin and ground. This external capacitor is tied in parallel with approximately 3 pF of internal capacitance at the compensation node. In addition, a small capacitance, CLEAD, in parallel with resistor R2, compensates for the capacitance at the inverting input of the amplifier.



<span id="page-11-5"></span>*Figure 36. Inverting Amplifier Connection Using External Shunt Compensation*



<span id="page-11-4"></span>*Figure 37. Noninverting Amplifier Connection Using External Shunt Compensation*

[Table 4](#page-12-1) gives the recommended C<sub>COMP</sub> and C<sub>LEAD</sub> values, as well as the corresponding slew rates and bandwidth. The capacitor values were selected to provide a small signal frequency response with <1 dB of peaking and <10% overshoot. Fo[r Table 4,](#page-12-1) ±15 V

supply voltages should be used[. Figure 38](#page-12-2) is a graphical extension o[f Table 4,](#page-12-1) which shows the slew rate/gain trade-off for lower closed-loop gains, when using the shunt compensation scheme.



*Figure 38. Value of CCOMP and Slew Rate vs. Noise Gain*

#### <span id="page-12-2"></span><span id="page-12-0"></span>**CURRENT FEEDBACK COMPENSATION**

$$
f_T = \frac{1}{2 \pi r_e C_{COMP}} = \frac{I}{2 \pi \frac{kT}{q} C_{COMP}}
$$



*CCOMP* is the compensation capacitance.

 $r_e$  is the inverse of the transconductance of the input transistors. *kT/q* approximately equals 26 mV at 27°C.

Because both fr and slew rate are functions of the same variables, the dynamic behavior of an amplifier is limited. Because

$$
Slew Rate = \frac{2I}{C_{COMP}}
$$

then

$$
\frac{Slew Rate}{f_T} = 4 \pi \frac{kT}{q}
$$

This shows that the slew rate is only 0.314 V/ $\mu$ s for every megahertz of bandwidth. The only way to increase the slew rate is to increase the  $f_T$ , and that is difficult because of process limitations. Unfortunately, an amplifier with a bandwidth of 10 MHz can only slew at 3.1 V/µs, which is barely enough to provide a full power bandwidth of 50 kHz.

00880-038 10 100 <b>NOISE GAIN</b> Figure 38. Value of C <sub>COMP</sub> and Slew Rate vs. Noise Gain						increase the fr, and that is difficult because of process limitations. Unfortunately, an amplifier with a bandwidth of 10 MHz can only slew at 3.1 $V/\mu s$ , which is barely enough to provide a full power bandwidth of 50 kHz.		
<b>CURRENT FEEDBACK COMPENSATION</b> Bipolar, nondegenerated, single-pole, and internally compensated amplifiers have their bandwidths defined as $f_T = \frac{1}{2 \pi r_e C_{COMP}} = \frac{1}{2 \pi \frac{kT}{a} C_{COMP}}$ where: $f_T$ is the unity-gain bandwidth of the amplifier. I is the collector current of the input transistor. Table 4. Component Selection for Shunt Compensation						The AD829 is especially suited to a form of current feedback compensation that allows for the enhancement of both the full power bandwidth and the slew rate of the amplifier. The voltage gain from the inverting input pin to the compensation pin is large; therefore, if a capacitance is inserted between these pins, the bandwidth of the amplifier becomes a function of its feed- back resistor and the capacitance. The slew rate of the amplifier is now a function of its internal bias (2I) and the compensation capacitance.		
<b>Follower Gain</b>	<b>Inverter Gain</b>	$R1(\Omega)$	$R2(\Omega)$			Slew Rate (V/µs)	-3 dB Small Signal Bandwidth (MHz)	
		Open	100	$C_{LEAD}$ (pF) 0	$C_{COMP}$ (pF) 68	16	66	
2	$-1$	1 k	1 <sup>k</sup>	5	25	38	71	
5	$-4$	511	2.0 <sub>k</sub>		7	90	76	
10	$-9$	226	2.05k	$\Omega$	3	130	65	
20	$-19$	105	2 k	0	0	230	55	
25	$-24$	105	2.49	0	0	230	39	

<span id="page-12-1"></span>**Table 4. Component Selection for Shunt Compensation**

Because the closed-loop bandwidth is a function of  $R<sub>F</sub>$  and CCOMP (se[e Figure 39\)](#page-13-0), it is independent of the amplifier closedloop gain, as shown i[n Figure 41.](#page-13-1) To preserve stability, the time constant of  $R_F$  and  $C_{\text{COMP}}$  needs to provide a bandwidth of <65 MHz. For example, with C<sub>COMP</sub> = 15 pF and R<sub>F</sub> = 1 kΩ, the small signal bandwidth of the AD829 is 10 MHz. [Figure 40](#page-13-2) shows that the slew rate is in excess of 60 V/ $\mu$ s. As shown in [Figure 41,](#page-13-1) the closed-loop bandwidth is constant for gains of −1 to −4; this is a property of the current feedback amplifiers.



<span id="page-13-0"></span>*Figure 39. Inverting Amplifier Connection Using Current Feedback Compensation*



<span id="page-13-2"></span>*Figure 40. Large Signal Pulse Response of Inverting Amplifier Using Current Feedback Compensation, CCOMP = 15 pF, C1 = 15 pF RF = 1 kΩ, R1 = 1 kΩ*



<span id="page-13-1"></span>*Figure 41. Closed-Loop Gain vs. Frequency for the Circuit o[f Figure 38](#page-12-2)*

[Figure 42](#page-13-3) is an oscilloscope photo of the pulse response of a unitygain inverter that has been configured to provide a small signal bandwidth of 53 MHz and a subsequent slew rate of 180 V/µs;  $R_F = 3 k\Omega$  and  $C_{COMP} = 1 pF$ [. Figure 43](#page-13-4) shows the excellent pulse response as a unity-gain inverter, this using component values of  $R_F = 1$  k $\Omega$  and  $C_{COMP} = 4$  pF.



<span id="page-13-3"></span>*Figure 42. Large Signal Pulse Response of the Inverting Amplifier Using Current Feedback Compensation, CCOMP = 1 pF, RF = 3 kΩ, R1 = 3 kΩ*



<span id="page-13-4"></span>*Figure 43. Small Signal Pulse Response of Inverting Amplified Using Current Feedback Compensation, CCOMP = 4 pF, RF = 1 kΩ, R1 = 1 kΩ*

[Figure 44](#page-14-1) an[d Figure 45](#page-14-2) show the closed-loop frequency response of the AD829 for different closed-loop gains and different supply voltages.



<span id="page-14-1"></span>*Figure 44. Closed-Loop Frequency Response for the Inverting Amplifier Using Current Feedback Compensation*



<span id="page-14-2"></span>*Figure 45. Closed-Loop Frequency Response vs. Supply for the Inverting Amplifier Using Current Feedback Compensation*

When a noninverting amplifier configuration using a current feedback compensation is needed, the circuit shown in Figure 46 is recommended. This circuit provides a slew rate twice that of the shunt compensated noninverting amplifier of [Figure 47](#page-14-3) at the expense of gain flatness. Nonetheless, this circuit delivers 95 MHz bandwidth with 1 dB flatness into a back-terminated cable, with a differential gain error of only 0.01% and a differential phase error of only 0.015 at 4.43 MHz.



*Figure 46. Noninverting Amplifier Connection Using Current Feedback Compensation*



<span id="page-14-3"></span>*Figure 47. Video Line Driver with a Flatness over Frequency Adjustment*

## <span id="page-14-0"></span>**LOW ERROR VIDEO LINE DRIVER**

The buffer circuit shown i[n Figure 47](#page-14-3) drives a back-terminated 75 Ω video line to standard video levels (1 V p-p), with 0.1 dB gain flatness to 30 MHz and with only 0.04° and 0.02% differential phase and gain at the 4.43 MHz PAL color subcarrier frequency. This level of performance, which meets the requirements for high definition video displays and test equipment, is achieved using only 5 mA quiescent current.

## <span id="page-15-0"></span>**HIGH GAIN VIDEO BANDWIDTH, 3-OP-AMP INSTRUMENTATION AMPLIFIER**

[Figure 48](#page-15-1) shows a 3-op-amp instrumentation amplifier circuit that provides a gain of 100 at video bandwidths. At a circuit gain of 100, the small signal bandwidth equals 18 MHz into a FET probe. Small signal bandwidth equals 6.6 MHz with a 50  $\Omega$  load. The 0.1% settling time is 300 ns.

The input amplifiers operate at a gain of 20, while the output op amp runs at a gain of 5. In this circuit, the main bandwidth limitation is the gain/bandwidth product of the output amplifier. Extra care should be taken while breadboarding this circuit because even a couple of extra picofarads of stray capacitance at the compensation pins of A1 and A2 will degrade circuit bandwidth.



<span id="page-15-1"></span>*Figure 48. High Gain Video Bandwidth, 3-Op-Amp In-Amp Circuit*

# <span id="page-16-0"></span>OUTLINE DIMENSIONS



*Dimensions shown in inches and (millimeters)*

**070606-A**



# CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS<br>(IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR<br>REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

*Figure 51. 8-Lead Ceramic Dual In-Line [CERDIP] (Q-8)*

*Dimensions shown in inches and (millimeters)*



*Figure 52. 20-Terminal Ceramic Leadless Chip Carrier [LCC]* CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS<br>(IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR<br>REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

*(E-20-1)* 

*Dimensions shown in inches and (millimeters)*

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# <span id="page-18-0"></span>**ORDERING GUIDE**



 $1 Z =$  RoHS Compliant Part.